



Sample &

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CSD16301Q2

SLPS235D-OCTOBER 2009-REVISED NOVEMBER 2016

CSD16301Q2 25-V N-Channel NexFET™ Power MOSFET

Features 1

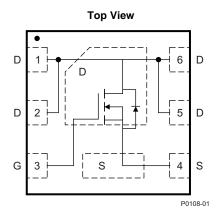
- Ultra-Low Q_a and Q_{ad}
- Low Thermal Resistance
- Lead-Free Terminal Plating
- **RoHS** Compliant
- Halogen Free
- SON 2-mm × 2-mm Plastic Package

2 Applications

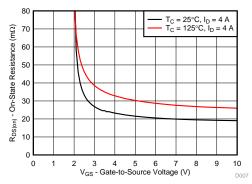
- **DC-DC Converters** •
- Battery and Load Management Applications

Description 3

This 25-V, 19-mΩ, 2-mm × 2-mm SON NexFET™ power MOSFET has been designed to minimize losses in power conversion and load management applications. The 2-mm × 2-mm SON package offers excellent thermal performance for the size of the package.



R_{DS(on)} vs V_{GS}



Product Summary

T _A = 25°	C	TYPICAL VA	UNIT							
V _{DS}	Drain-to-Source Voltage	25		V						
Qg	Gate Charge Total (4.5 V) 2									
Q _{gd}	Gate Charge Gate-to-Drain	0.4	nC							
		$V_{GS} = 3 V$	27							
R _{DS(on)}	Drain-to-Source On Resistance	$V_{GS} = 4.5 V$	23	mΩ						
		$V_{GS} = 8 V$	19							
V _{GS(th)}	Threshold Voltage 1.1									

Device Information⁽¹⁾

DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD16301Q2	3000		SON	Таре
CSD16301Q2T	250	7-Inch Reel	2.00-mm × 2.00-mm Plastic Package	and Reel

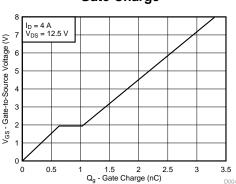
(1) For all available packages, see the orderable addendum at the end of the data sheet.

T _A = 2	5°C	VALUE	UNIT	
V_{DS}	Drain-to-Source Voltage	25	V	
V_{GS}	Gate-to-Source Voltage	+10 /8	V	
	Continuous Drain Current (Package Limited)	5		
I _D	Continuous Drain Current (Silicon Limited), $T_{C} = 25^{\circ}C$	20	А	
	Continuous Drain Current ⁽¹⁾	8.2		
I _{DM}	Pulsed Drain Current ⁽²⁾	85	А	
р	Power Dissipation ⁽¹⁾	2.5	W	
PD	Power Dissipation, $T_C = 25^{\circ}C$	15	vv	
T _J , T _{STG}	Operating Junction, Storage Temperature	–55 to 150	ů	
E _{AS}	Avalanche Energy, Single Pulse I _D = 14 A, L = 0.1 mH, R _G = 25 Ω	10	mJ	
•	•		•	

Absolute Maximum Ratings

(1) Typical $R_{\theta JA}$ = 50°C/W on a 1-in², 2-oz Cu pad on a 0.06-in thick FR4 PCB.

(2) Max R_{θ JC} = 8.4°C/W, pulse duration \leq 100 μ s, duty cycle \leq 1%.



Gate Charge

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.



2

Table of Contents

- 1 Features 1
- 2
 Applications
 1

 3
 Description
 1

 4
 Revision History
 2

 5
 Specifications
 3

 5.1
 Electrical Characteristics
 3

 5.2
 Thermal Information
 3

 5.3
 Typical MOSFET Characteristics
 4

 6
 Device and Documentation Support
 7
 - 6.1 Receiving Notification of Documentation Updates.... 7

Changes from Revision C (July 2011) to Revision D

6.3 Trademarks 7 Electrostatic Discharge Caution 7 6.4 Glossary 7 6.5 7 Mechanical, Packaging, and Orderable Information 8 7.1 7.2 7.3 Recommended Stencil Pattern 10 Q2 Tape and Reel Information..... 11 7.4

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

1
1
1
1
3
4
5
7
8

Changes from Original (October 2009) to Revision A Page

•	Changed the Electrical Characteristics table -	V _{GS(th)} MAX value From: 1.4V To 1.55V	3
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Page

CSD16301Q2 SLPS235D - OCTOBER 2009-REVISED NOVEMBER 2016

5 Specifications

5.1 Electrical Characteristics

 $T_A = 25^{\circ}C$ (unless otherwise specified)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS					
BV _{DSS}	Drain-to-source voltage	V _{GS} = 0 V, I _D = 250 μA	25			V
I _{DSS}	Drain-to-source leakage current	V _{GS} = 0 V, V _{DS} = 20 V			1	μA
I _{GSS}	Gate-to-source leakage current	V _{DS} = 0 V, V _{GS} = +10/-8 V			100	nA
V _{GS(th)}	Gate-to-source threshold voltage	$V_{DS} = V_{GS}$, $I_{DS} = 250 \ \mu A$	0.9	1.1	1.55	V
		$V_{GS} = 3 V$, $I_{DS} = 4 A$		27	34	
R _{DS(on)}	Drain-to-source on resistance	$V_{GS} = 4.5 \text{ V}, \text{ I}_{DS} = 4 \text{ A}$		23	29	mΩ
		$V_{GS} = 8 V, I_{DS} = 4 A$		19	24	
9 _{fs}	Transconductance	V _{DS} = 15 V, I _{DS} = 4 A		16.5		S
DYNAMI	C CHARACTERISTICS					
C _{ISS}	Input capacitance			260	340	pF
C _{OSS}	Output capacitance	$V_{GS} = 0 V, V_{DS} = 12.5 V, f = 1 MHz$		165	215	pF
C _{RSS}	Reverse transfer capacitance			13	17	pF
R _g	Series gate resistance			1.3	2.6	Ω
Qg	Gate charge total (4.5 V)			2.0	2.8	nC
Q _{gd}	Gate charge gate-to-drain	V 10.V L 1.A		0.4		nC
Q _{gs}	Gate charge gate-to-source	$V_{DS} = 10 \text{ V}, \text{ I}_{DS} = 4 \text{ A}$		0.6		nC
Qg(th)	Gate charge at Vth			0.3		nC
Q _{OSS}	Output charge	$V_{DS} = 12.5 V, V_{GS} = 0 V$		3.0		nC
t _{d(on)}	Turnon delay time			2.7		ns
t _r	Rise time	V _{DS} = 12.5 V, V _{GS} = 4.5 V, I _{DS} = 4 A		4.4		ns
t _{d(off)}	Turnoff delay time	$R_G = 2 \Omega$		4.1		ns
t _f	Fall time			1.7		ns
DIODE C	CHARACTERISTICS					
V_{SD}	Diode forward voltage	$I_{DS} = 4 \text{ A}, V_{GS} = 0 \text{ V}$		0.8	1	V
Q _{rr}	Reverse recovery charge	$V_{1} = 125V_{1} = 40$ di/dt = 200 M/m		5.1		nC
t _{rr}	Reverse recovery time	V_{DD} = 12.5 V, I _F = 4 A, di/dt = 200 A/µs		11		ns

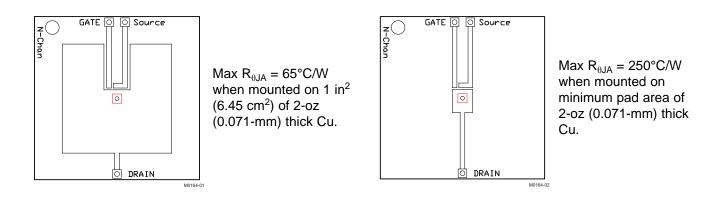
5.2 Thermal Information

 $T_A = 25^{\circ}C$ (unless otherwise stated)

	THERMAL METRIC	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-case thermal resistance ⁽¹⁾			8.4	°C/W
R_{\thetaJA}	Junction-to-ambient thermal resistance ⁽¹⁾⁽²⁾			65	°C/W

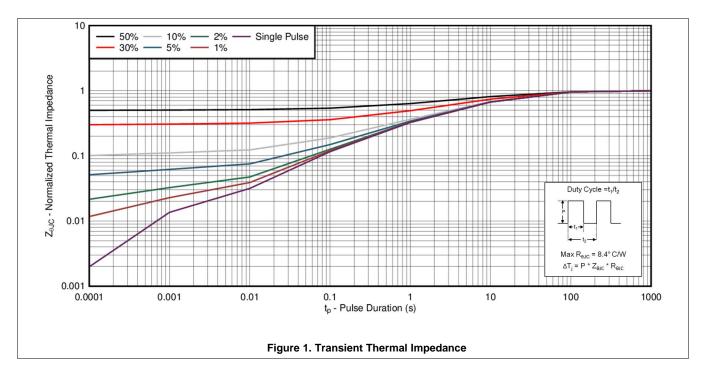
(1) R_{θJC} is determined with the device mounted on a 1-in² (6.45-cm²), 2-oz (0.071-mm) thick Cu pad on a 1.5-in x 1.5-in (3.81-cm x 3.81-cm), 0.06-in (1.52-mm) thick FR4 PCB. R_{θJC} is specified by design, whereas R_{θJA} is determined by the user's board design.
 (2) Device mounted on FR4 material with 1-in² (6.45-cm²), 2-oz (0.071-mm) thick Cu.





5.3 Typical MOSFET Characteristics

 $T_A = 25^{\circ}C$ (unless otherwise specified)

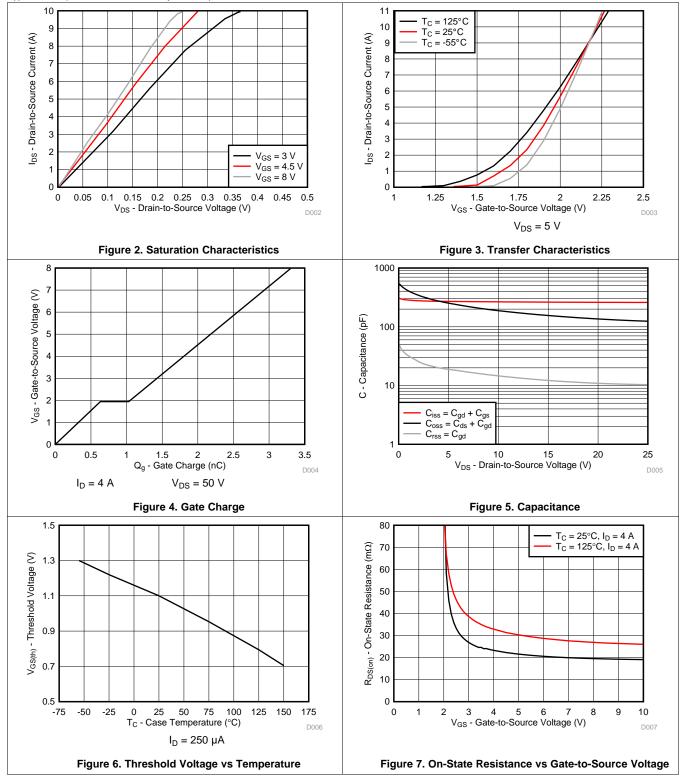


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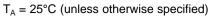
Typical MOSFET Characteristics (continued)

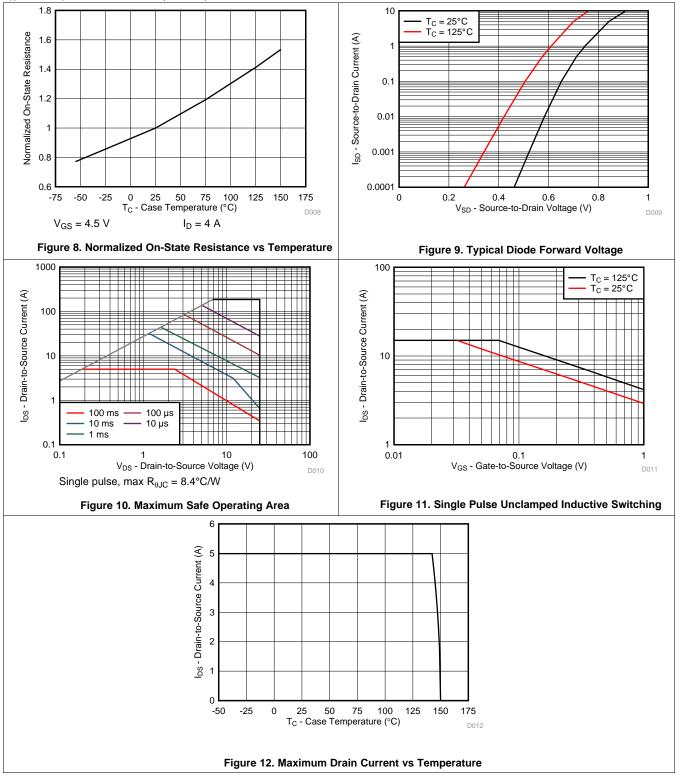
 $T_A = 25^{\circ}C$ (unless otherwise specified)





Typical MOSFET Characteristics (continued)







6 Device and Documentation Support

6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

6.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.3 Trademarks

NexFET, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

6.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

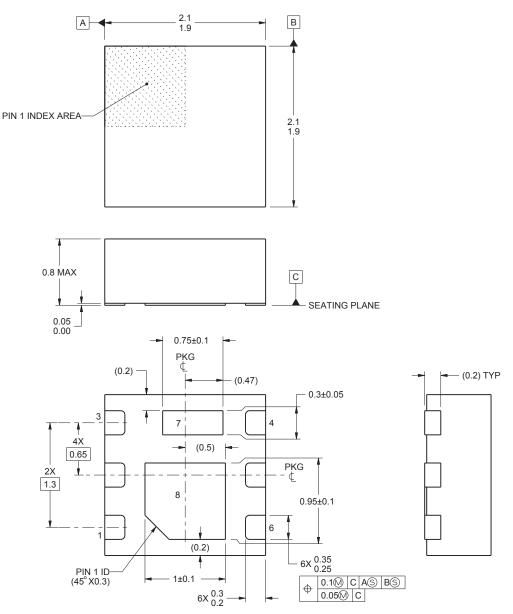
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7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

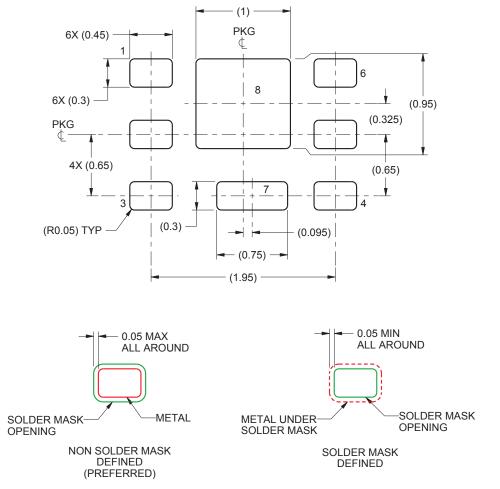
7.1 Q2 Package Dimensions



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pads must be soldered to the printed circuit board for thermal and mechanical performance.



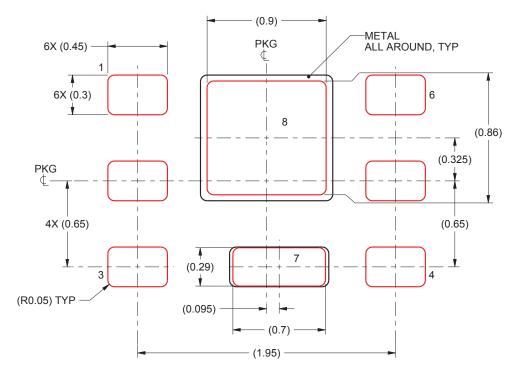
7.2 Recommended PCB Pattern



- 1. For recommended circuit layout for PCB designs, see *Reducing Ringing Through PCB Layout Techniques* (SLPA005).
- 2. This package is designed to be soldered to a thermal pad on the board. For more information, see *QFN/SON PCB Attachment* (SLUA271).



7.3 Recommended Stencil Pattern



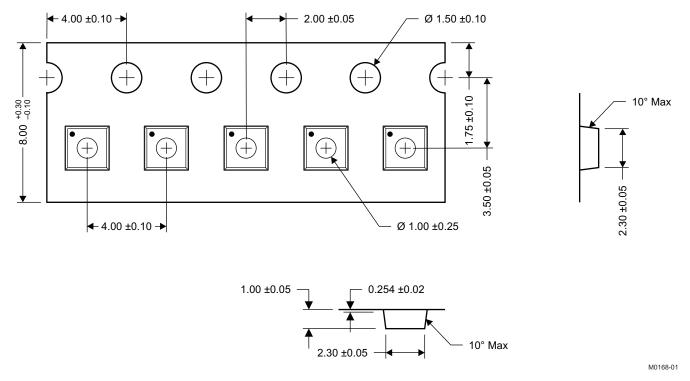
- 1. All linear dimensions are in millimeters.
- 2. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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7.4 Q2 Tape and Reel Information



Notes:

- 1. Measured from centerline of sprocket hole to centerline of pocket.
- 2. Cumulative tolerance of 10 sprocket holes is ± 0.2 .
- 3. Other material available.
- 4. Typical SR of form tape Max 10⁹ OHM/SQ.
- 5. All dimensions are in mm, unless otherwise specified.



17-Feb-2016

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD16301Q2	ACTIVE	WSON	DQK	6	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 150	1631	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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